5Ω Max Ron, 4-/8-Channel ±15V/12V/±5V Multiplexers

Preliminary Technical Data

ADG1408/ADG1409

FEATURES

5Ω Max On Resistance
0.5Ω Max On Resistance Flatness
33 V Supply Maximum Ratings
Fully specified at ±15V/12V/±5V
3V Logic Compatible Inputs
Rail-to-Rail Operation
Break-Before-Make Switching Action
16-Lead TSSOP Packages
Typical Power Consumption (< 0.03 µW)

APPLICATIONS

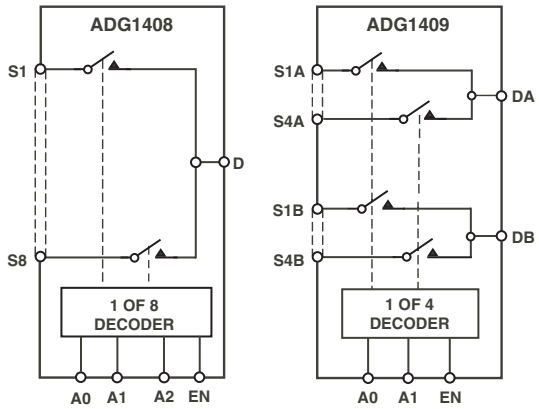
Relay Replacement
Audio and Video Routing
Automatic Test Equipment
Data Acquisition Systems
Battery-Powered Systems
Sample-and-Hold Systems
Communication Systems

GENERAL DESCRIPTION

The ADG1408 and ADG1409 are monolithic CMOS analog multiplexers comprising eight single channels and four differential channels, respectively. The ADG1408 switches one of eight inputs to a common output as determined by the 3-bit binary address lines A0, A1, and A2. The ADG1409 switches one of four differential inputs to a common differential output as determined by the 2-bit binary address lines A0 and A1. An EN input on both devices is used to enable or disable the device. When disabled, all channels are switched OFF.

The ADG1408/ADG1409 are designed on an enhanced CMOS process that provides low power dissipation yet gives high switching speed and low on resistance. Each channel conducts equally well in both directions when ON and has an input signal range that extends to the supplies. In the OFF condition, signal levels up to the supplies are blocked. All channels exhibit break-before- make switching action, preventing momentary shorting when switching channels. Inherent in the design is low charge injection for minimum transients when switching the digital inputs.

FUNCTIONAL BLOCK DIAGRAMS



SWITCHES SHOWN FOR A "1" LOGIC INPUT

PRODUCT HIGHLIGHTS

1. 5Ω Max On Resistance
2. 0.5Ω Max On Resistance Flatness
3. 3V Logic Compatible Digital Input
   V_{IH} = 2.0V, V_{IL} = 0.8V
4. 16 Lead TSSOP package

RevPrA

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REVISION HISTORY

ADG1408/ADG1409—SPECIFICATIONS

DUAL SUPPLY[1]

Table 1. V_{DD} = +15 V ± 10%, V_{SS} = –15 V ± 10%, GND = 0 V, unless otherwise noted.

Parameter	+25°C	–40°C to +85°C	–40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			V_{SS} to V_{DD}	V	
R_{ON}	3			Ω typ	V_D = ±10 V, I_S = –10 mA
	4	5	5	Ω max	
R_{ON} Flatness				Ω typ	V_D = +10 V, –10 V
	0.5			Ω max	
ΔR_{ON}	0.5			Ω typ	V_D = +10 V, –10 V
				Ω max	
LEAKAGE CURRENTS					
Source OFF Leakage I_S (OFF)	±0.01			nA typ	V_D = ±10 V, V_S = –10 V; Test Circuit 2
	±0.5	±2.5	±50	nA max	±0.5
Drain OFF Leakage I_D (OFF)					V_D = ±10 V; V_S = ±10 V;
ADG1408	±1	±100	±100	nA max	Test Circuit 3
ADG1409	±1	±50	±50	nA max	
Channel ON Leakage I_D, I_S (ON)					V_S = V_D = ±10 V;
ADG1408	±1	±100	±100	nA max	Test Circuit 4
ADG1409	±1	±50	±50	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}		2.0	2.0	V min	
Input Low Voltage, V_{INL}		0.8	0.8	V max	
Input Current					
I_{INL} or I_{INH}	±0.005			µA max	V_{IN}= V_{INL} or V_{INH}
		±0.5	±0.5	µA max	
C_{IN}, Digital Input Capacitance	5			pF typ	
DYNAMIC CHARACTERISTICS[2]					
$t_{TRANSITION}$	80	120	120	ns typ	R_L = 300 Ω, C_L = 35 pF;
		250	250	ns max	V_{S1} = ±10 V, V_{S8} = ±10 V; Test Circuit 5
T_{BBM}	10	10	10	ns typ	R_L = 300 Ω, C_L = 35 pF;
			1	ns min	V_S = 10 V; Test Circuit 6
t_{ON}(EN)	85	125	125	ns typ	R_L = 300 Ω C_L = 35 pF;
	150	225	225	ns max	V_S = 5 V; Test Circuit 7
t_{OFF}(EN)	40	65	65	ns typ	R_L = 300 Ω, C_L = 35 pF;
		150	150	ns max	V_S = 5 V; Test Circuit 7
Charge Injection	20		20	pC typ	V_S = 0 V, R_S = 0 Ω, C_L = 10 nF; Test Circuit 8
OFF Isolation	75			dB typ	R_L = 1 kΩ, f = 100 kHz; V_{EN} = 0 V; Test Circuit 9
Channel-to-Channel Crosstalk	85			dB typ	RL = 1 kΩ, f = 100 kHz; Test Circuit 10
Total Harmonic Distortion, THD + N	0.002			% typ	R_L = 600 Ω, 5Vrms; f=20Hz to 20kHz
-3dB Bandwidth	50			MHz typ	R_L = 300 Ω, C_L = 5 pF; Test Circuit 10
					Test Circuit 10
C_S (OFF)	15			pF typ	f = 1 MHz
C_D (OFF)					f = 1 MHz

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ADG1408	100			pF typ	
ADG1409	50			pF typ	
C_D, C_S(ON)					f = 1 MHz
ADG1408	150			pF typ	
ADG1409	75			pF typ	
POWER REQUIREMENTS					V_{DD} = +16.5V, V_{SS} = -16.5V
I_{DD}	0.001			µA typ	Digital Inputs= 0 V or V_{DD}
		5	5	µA max	
I_{DD}	150			µA typ	Digital Inputs= 5 V
			300	µA max	
I_{SS}	0.001			µA typ	Digital Inputs= 0 V or V_{DD}
		5	5	µA max	
I_{GND}	0.001			µA typ	Digital Inputs= 0 V or V_{DD}
		5	5	µA max	
I_{GND}	150			µA typ	Digital Inputs= 5 V
		5	300	µA max	

[1] Temperature ranges are as follows: B Version: −40°C to +85°C; T Version: −40°C to +125°C.
[2] Guaranteed by design, not subject to production test.

SINGLE SUPPLY[1]

Table 2. V_{DD} = 12 V V ± 10%,, V_{SS} = 0 V, GND = 0 V, unless otherwise noted.

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 to V_{DD}	V	
R_{ON}	6			Ω typ	V_D = 3 V, 10 V, I_S = −1 mA
	7	8	9	Ω max	
R_{ON} Flatness				Ω typ	V_D = 3 V, 10 V, I_S = −1 mA
	1.5			Ω max	
ΔR_{ON}	0.5			Ω typ	V_D = 3 V, 10 V, I_S = −1 mA
				Ω max	
Channel ON Leakage I_D, I_S (ON)					V_S = V_D = 8 V/0 V;
ADG1408	±1	±100	±100	nA max	Test Circuit 4
ADG1409	±1	±50	±50	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}		2.0	2.0	V min	
Input Low Voltage, V_{INL}		0.8	0.8	V max	
Input Current					
I_{INL} or I_{INH}		±10	±10	µA max	V_{IN} = 0 or V_{DD}
C_{IN}, Digital Input Capacitance	8			pF typ	f = 1 MHz
DYNAMIC CHARACTERISTICS[2]					
$t_{TRANSITION}$	130			ns typ	R_L = 300 Ω, C_L = 35 pF; V_{S1} = 8 V/0 V, V_{S8} = 0 V/8 V; Test Circuit 5
T_{BBM}	10			ns typ	R_L = 300 Ω, C_L = 35 pF;
			1	ns min	V_S = 5 V; Test Circuit 6
t_{ON} (EN)	140			ns typ	R_L = 300 Ω C_L = 35 pF; V_S = 5 V; Test Circuit 7
t_{OFF} (EN)	60			ns typ	R_L = 300 Ω, C_L = 35 pF; V_S = 5 V; Test Circuit 7
Charge Injection	5			pC typ	V_S = 0 V, R_S = 0Ω, C_L = 10 nF;

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
					Test Circuit 8
OFF Isolation	−75			dB typ	R_L = 1 kΩ f = 100 kHz;
					V_{EN} = 0 V; Test Circuit 9
Channel-to-Channel Crosstalk	85			dB typ	R_L = 1 kΩ, f = 100 kHz;
					Test Circuit 10
Total Harmonic Distortion, THD + N	0.002			% typ	R_L = 600 Ω, 5Vrms; f=20Hz to 20kHz
-3dB Bandwidth	50			MHz typ	R_L = 300 Ω, C_L = 5 pF; Test Circuit 10
C_S (OFF)	15			pF typ	f = 1 MHz
C_D (OFF)					f = 1 MHz
ADG1408	100			pF typ	
ADG1409	50			pF typ	
C_D, C_S (ON)					f = 1 MHz
ADG1408	150			pF typ	
ADG1409	75			pF typ	
POWER REQUIREMENTS					V_{DD} = 13.2V
I_{DD}		1	1	µA typ	Digital Inputs= 0 V or V_{DD}
		5	5	µA max	
I_{DD}	150			µA typ	Digital Inputs= 5
			300	µA max	

[1] Temperature ranges are as follows: B Version: −40°C to +85° ; T Version: −55°C to +125°.
[2] Guaranteed by design, not subject to production test.

DUAL SUPPLY[1]

Table 3. V_{DD} = +5 V ± 10%, V_{SS} = −5 V ± 10%, GND = 0 V, unless otherwise noted.

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			V_{SS} to V_{DD}	V	
R_{ON}	6			Ω typ	V_D = ±3.3 V, I_S = −10 mA
	7	8	10	Ω max	
ΔR_{ON}	0.5			Ω max	V_D = +3.3 V, −3.3 V
LEAKAGE CURRENTS					
Source OFF Leakage I_S (OFF)	±0.01			nA typ	V_D = ±3.3 V, V_S = −3.3 V; Test Circuit 2
	±0.5	±2.5	±50	nA max	
Drain OFF Leakage I_D (OFF)					V_D = ±3.3. V; V_S = ±3.3 V;
ADG1408	±1	±100	±100	nA max	Test Circuit 3
ADG1409	±1	±50	±50	nA max	
Channel ON Leakage I_D, I_S (ON)					V_S = V_D = ±3.3 V;
ADG1408	±1	±100	±100	nA max	Test Circuit 4
ADG1409	±1	±50	±50	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}		2.0	2.0	V min	
Input Low Voltage, V_{INL}		0.8	0.8	V max	
Input Current					
I_{INL} or I_{INH}	±0.005			µA max	V_{IN}= V_{INL} or V_{INH}
		±0.5	±0.5	µA max	
C_{IN}, Digital Input Capacitance	5			pF typ	
DYNAMIC CHARACTERISTICS[2]					
$t_{TRANSITION}$		120	120	ns typ	R_L = 300 Ω, C_L = 35 pF;

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
		250	250	ns max	V_{S1} = ±10 V, V_{S8} = ±10 V; Test Circuit 5
T_{BBM}				ns typ	R_L = 300 Ω, C_L = 35 pF;
			1	ns min	V_S = 5 V; Test Circuit 6
t_{ON}(EN)	85	125	125	ns typ	R_L = 300 Ω C_L = 35 pF;
	150	225	225	ns max	V_S = 5 V; Test Circuit 7
t_{OFF}(EN)		65	65	ns typ	R_L = 300 Ω, C_L = 35 pF;
		150	150	ns max	V_S = 5 V; Test Circuit 7
Charge Injection	20			pC typ	V_S = 0 V, R_S = 0 Ω, C_L = 10 nF; Test Circuit 8
OFF Isolation	−75		−75	dB typ	R_L = 1 kΩ, f = 100 kHz; V_{EN} = 0 V; Test Circuit 9
Channel-to-Channel Crosstalk	85		85	dB typ	RL = 1 kΩ, f = 100 kHz; Test Circuit 10
Total Harmonic Distortion, THD + N	0.002			% typ	R_L = 600 Ω, 5Vrms; f=20Hz to 20kHz
-3dB Bandwidth	50			MHz typ	R_L = 300 Ω, C_L = 5 pF; Test Circuit 10
					Test Circuit 10
C_S (OFF)	15			pF typ	f = 1 MHz
C_D (OFF)					f = 1 MHz
ADG1408	100			pF typ	
ADG1409	50			pF typ	
C_D, C_S(ON)					f = 1 MHz
ADG1408	150			pF typ	
ADG1409	75			pF typ	
POWER REQUIREMENTS					V_{DD} = +16.5V, V_{SS} = -16.5V
I_{DD}	0.001			µA typ	Digital Inputs= 0 V or V_{DD}
		5	5	µA max	
I_{DD}	150			µA typ	Digital Inputs= 5 V
			300	µA max	
I_{SS}	0.001			µA typ	Digital Inputs= 0 V or V_{DD}
		5	5	µA max	
I_{GND}	0.001			µA typ	Digital Inputs= 0 V or V_{DD}
		5	5	µA max	
I_{GND}	150			µA typ	Digital Inputs= 5 V
		5	300	µA max	

[1] Temperature ranges are as follows: B Version: −40°C to +85°C; Y Version: −40°C to +125°C.
[2] Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS[1]

Table 4. Absolute Maximum Ratings (T_A = 25°C, unless otherwise noted.)

Parameter	Rating
V_{DD} to V_{SS}	36 V
V_{DD} to GND	−0.3 V to +25 V
V_{SS} to GND	+0.3 V to −25 V
Analog, Digital Inputs[2]	V_{SS} − 0.3 V to V_{DD} + 0.3V or 20 mA, Whichever Occurs First
Continuous Current, S or D	30 mA
Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle max)	100 mA
Operating Temperature Range	
Industrial (B Version)	−40° C to +85°C
Automotive (Y Version)	−40° C to +125°C
Storage Temperature Range	−65° C to +150°C
Junction Temperature	150°C

Parameter	Rating
TSSOP Package, Power Dissipation	450 mW
θ_{JA}, Thermal Impedance	150.4°C/W
θ_{JC}, Thermal Impedance	50°C/W
Lead Temperature, Soldering	
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C

[1] Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

[2] Overvoltages at A, EN, S, or D will be clamped by internal diodes. Current should be limited to the maximum ratings given.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS - TSSOP

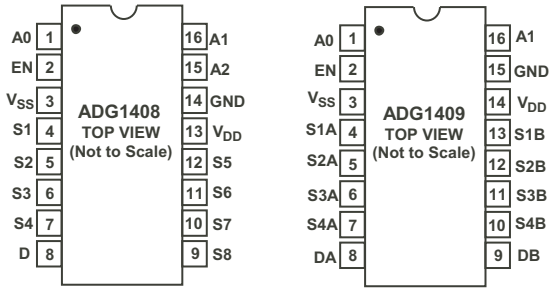


Figure 1. Pin Configurations - TSSOP

Table 5. ADG408 Truth Table

A2	A1	A0	EN	ON SWITCH
X	X	X	0	NONE
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

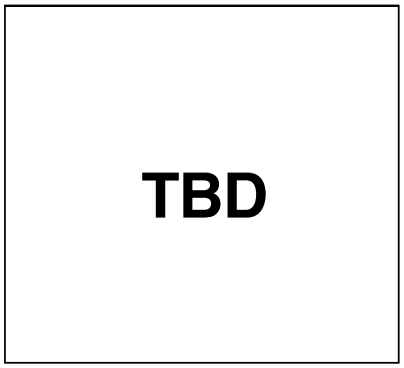
Table 6. ADG409 Truth Table

AI	A0	EN	ON SWITCH PAIR
X	X	0	NONE
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

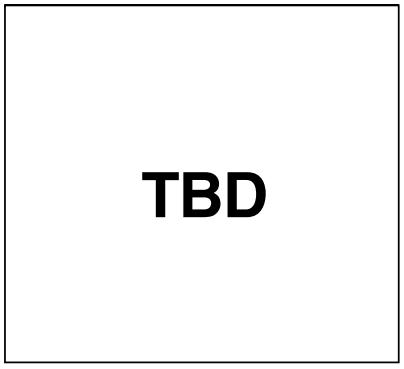
TERMINOLOGY

V_{DD}	Most positive power supply potential.
V_{SS}	Most negative power supply potential in dual supplies. In single supply applications, it may be connected to ground.
GND	Ground (0 V) reference.
R_{ON}	Ohmic resistance between D and S.
ΔR_{ON}	Difference between the R_{ON} of any two channels.
I_S (OFF)	Source leakage current when the switch is off.
I_D (OFF)	Drain leakage current when the switch is off.
I_D, I_S (ON)	Channel leakage current when the switch is on.
V_D (V_S)	Analog voltage on terminals D, S.
C_S (OFF)	Channel input capacitance for OFF condition.
C_D (OFF)	Channel output capacitance for OFF condition.
C_D, C_S (ON)	ON switch capacitance.
CI_N	Digital input capacitance.
t_{ON} (EN)	Delay time between the 50% and 90% points of the digital input and switch ON condition.
t_{OFF} (EN)	Delay time between the 50% and 90% points of the digital input and switch OFF condition.
$t_{TRANSITION}$	Delay time between the 50% and 90% points of the digital inputs and the switch ON condition when switching from one address state to another.
t_{OPEN}	OFF time measured between the 80% point of both switches when switching from one address state to another.
V_{INL}	Maximum input voltage for Logic 0.
V_{INH}	Minimum input voltage for Logic 1.
I_{INL} (I_{INH})	Input current of the digital input.
I_{DD}	Positive supply current.
I_{SS}	Negative supply current.
Off Isolation	A measure of unwanted signal coupling through an OFF channel.
Charge Injection	A measure of the glitch impulse transferred from the digital input to the analog output during switching.
Bandwidth	The frequency at which the output is attenuated by 3dBs.
On Response	The Frequency response of the "ON" switch.
THD + N	The ratio of the harmonic amplitude plus noise of the signal to the fundamental.

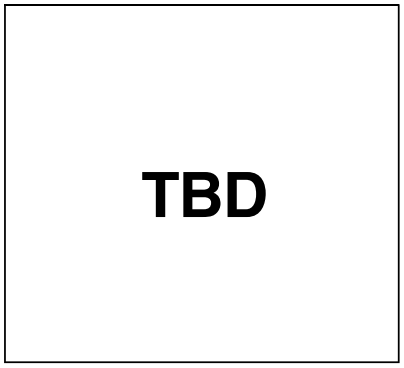
TYPICAL PERFORMANCE CHARACTERISTICS



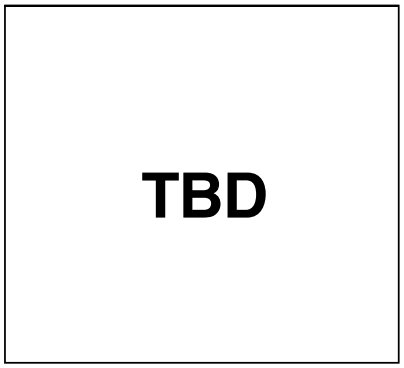
TPC 1. On Resistance as a Function of VD(VS) for for Single Supply



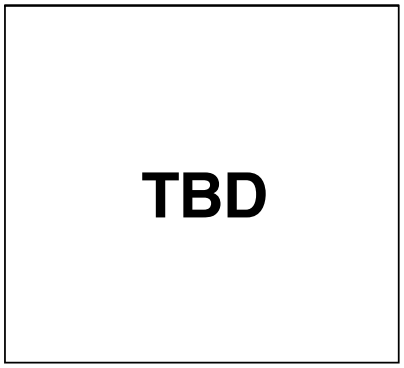
TPC 2. On Resistance as a Function of VD(VS) for Dual Supply



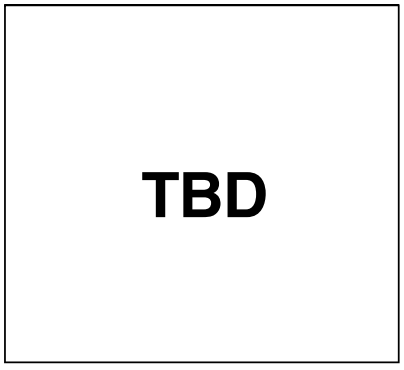
TPC 3. On Resistance as a Functionof VD(VS) for Different Temperatures, Single Supply



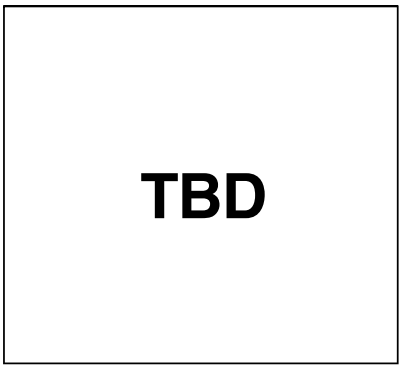
TPC 4. On Resistance as a Functionof VD(VS) for Different Temperatures, Single Supply



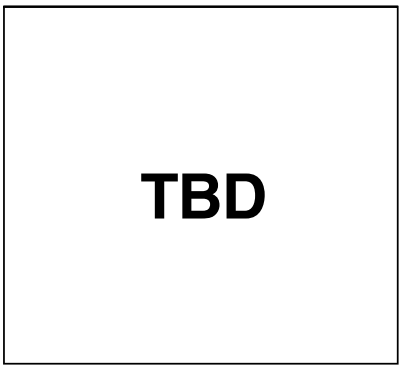
TPC 5. On Resistance as a Functionof VD(VS) for Different Temperatures, Dual Supply



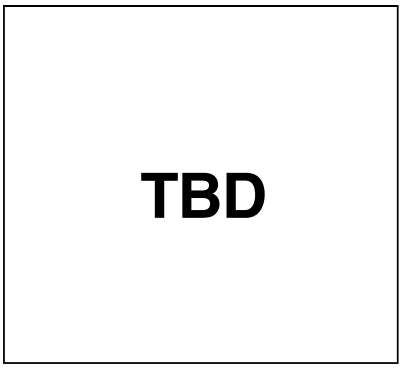
TPC 6. Leakage Currents as a Function of V_D (V_S)



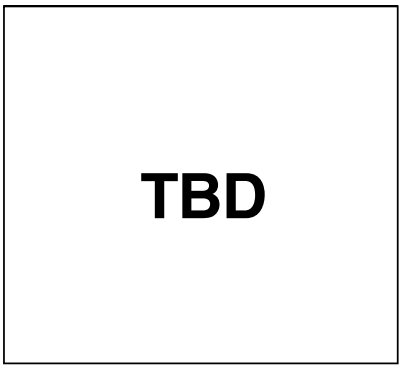
TPC 7. Leakage Currents as a function of Temperature



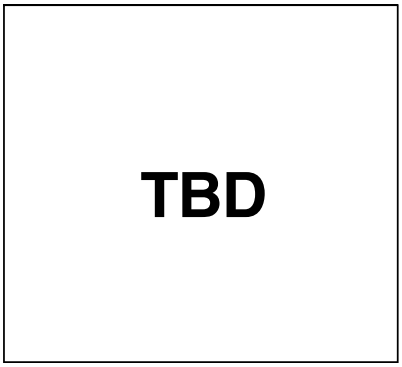
TPC 8 Supply Currents vs. Input Switching Frequency



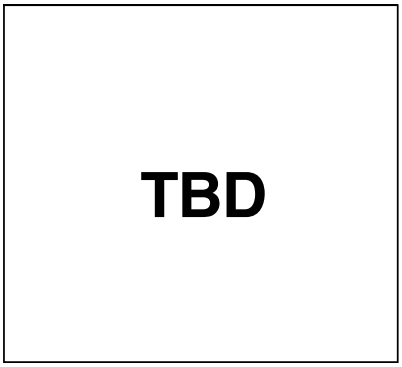
TPC 9 . Charge Injection vs. Source Voltage



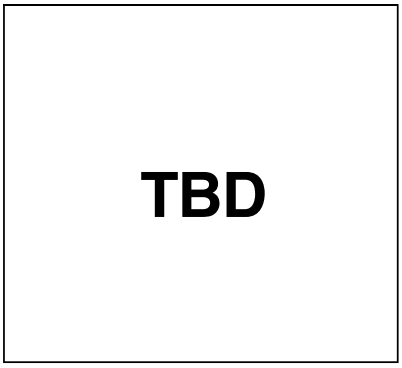
TPC 10. TON/TOFF Times vs. Temperature)



TPC 11 Off Isolation vs. Frequency



TPC 12 Crosstalk vs. Frequency

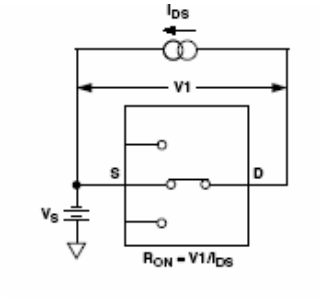


TPC 13. On Response vs. Frequency

TBD

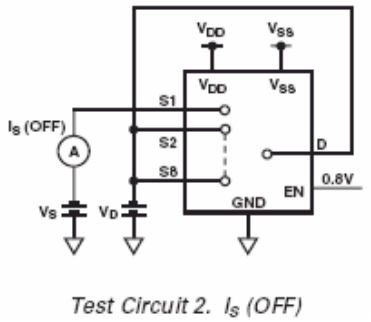
TPC 14. THD + N vs. Frequency

TEST CIRCUITS



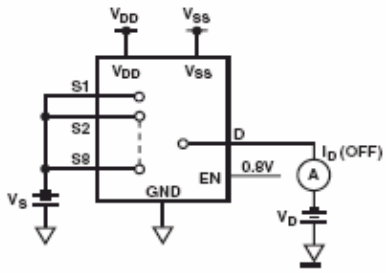
Test Circuit 1. On Resistance

Figure 2. Test Circuit 1. On Resistance



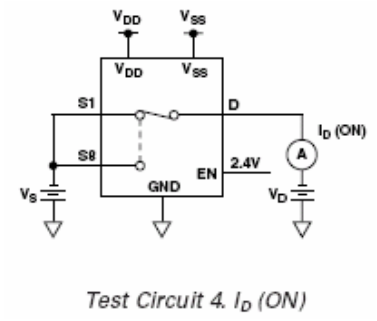
Test Circuit 2. I_S (OFF)

Figure 3. Test Circuit 2. I_S (OFF)



Test Circuit 3. I_D (OFF)

Figure 4. Test Circuit 3. I_D (OFF)



Test Circuit 4. I_D (ON)

Figure 5. Test Circuit 4. I_D (ON)

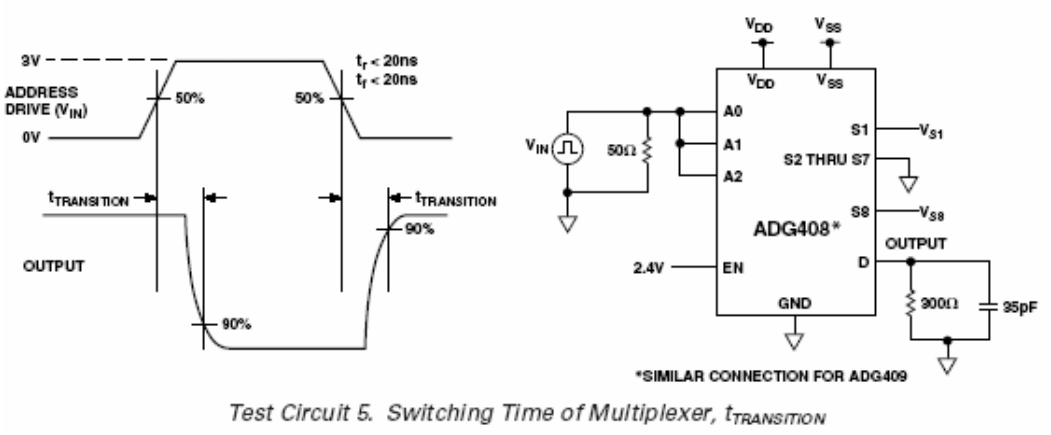


Figure 6. Test Circuit 5. Switching Time of Multiplexer, $t_{TRANSITION}$

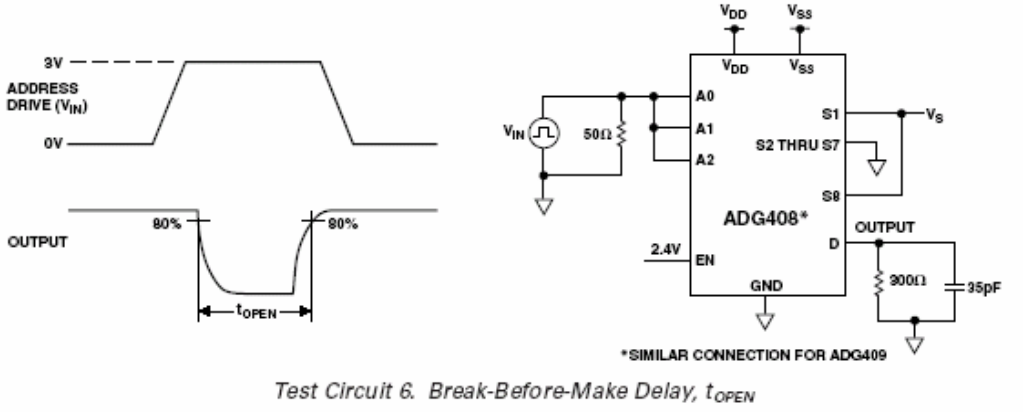


Figure 7. Test Circuit 6. Break-Before-Make Delay, t_{OPEN}

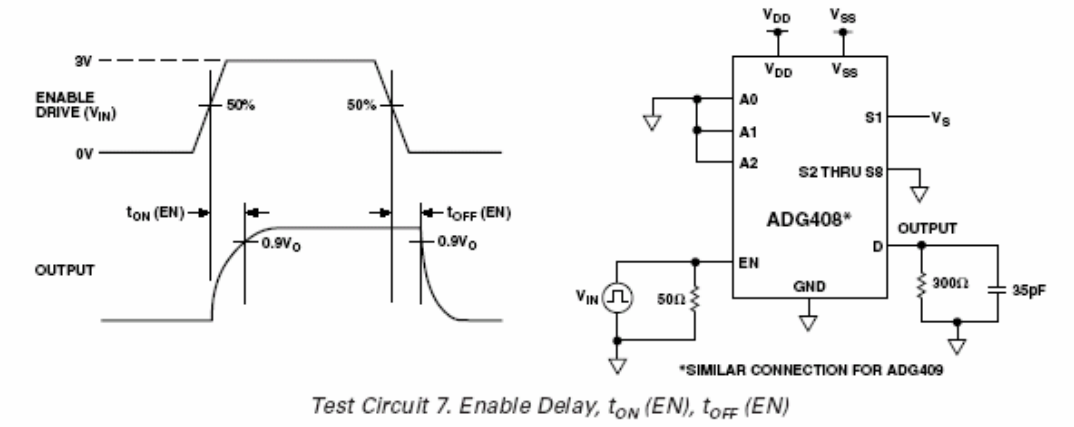


Figure 8. Test Circuit 7. Enable Delay, t_{ON} (EN), t_{OFF} (EN)

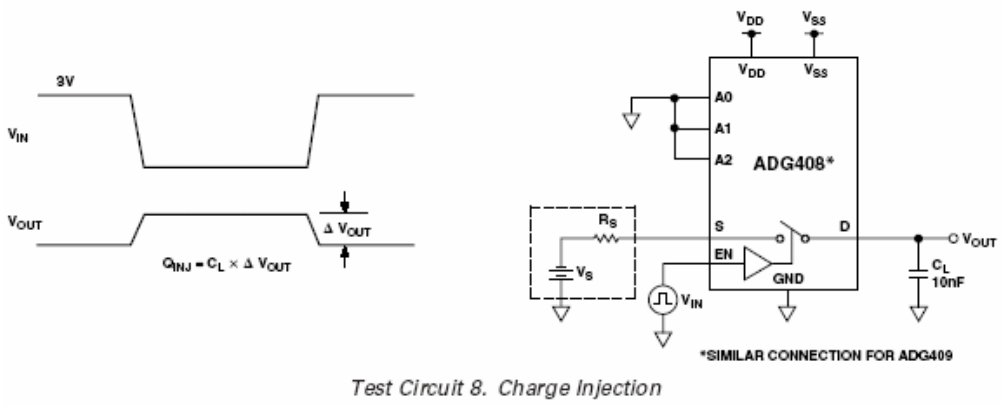


Figure 9. Test Circuit 8. Charge Injection

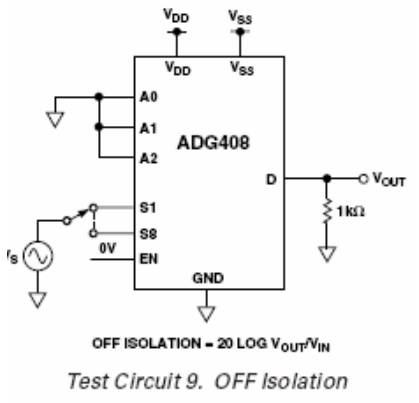


Figure 10. Test Circuit 9. OFF Isolation

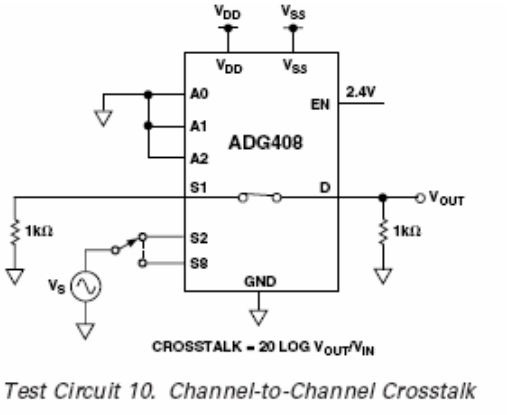


Figure 11. Test Circuit 10. Channel-to-Channel Crosstalk

OUTLINE DIMENSIONS

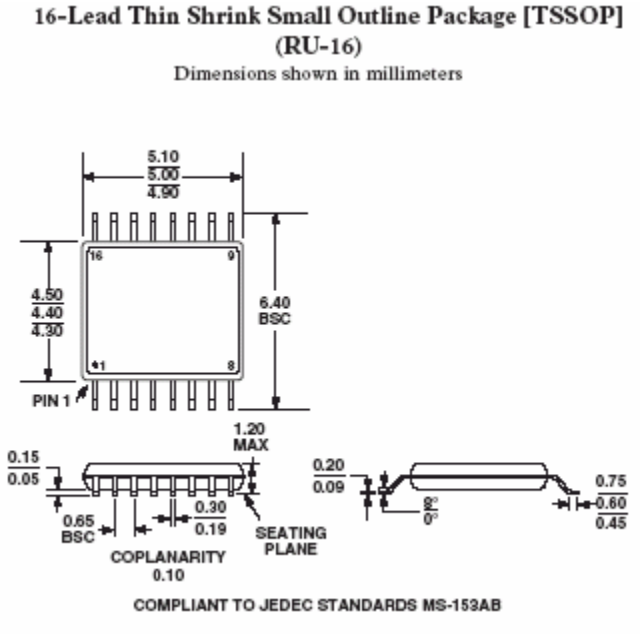


Figure 12. 16-Lead Thin Shrink Small Outline Package [TSSOP] (RU-16)

ORDERING GUIDE

Model	Temperature Range	Package Option[1]
ADG1408BRU	−40°C to +125°C	RU-16
ADG1409BRU	−40°C to +125°C	RU-16

[1] RU = Thin Shrink Small Outline Package (TSSOP)